## NSN 5962-01-316-9106

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-316-9106

**Body Length:** 1.060 inches **Body Width:** Between 0.220 inches and 0.310 inches **Body Height:** Between 0.130 inches and 0.185 inches **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** Training set, countermeasures signals an/msr-t4 **Features Provided:** Hermetically sealed and burn in and programmable and monolithic and ultraviolet erasable **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:** 10 input **Case Outline Source And Designator:** D-8 mil-m-38510 **Current Rating Per Characteristic:** 24.00 milliamperes output sink **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 5.0 volts power source **Time Rating Per Chacteristic:** 40.00 nanoseconds propagation delay time, low to high level output and 40.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Pal **Test Data Document:** 

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

**Terminal Type And Quantity:** 

20 printed circuit

Shelf Life:

N/a

## NSN 5962-01-316-9106

Memory Microcircuit - Page 2 of 2



**Unit Of Measure:** 

--

Demilitarization:

Yes - demil/mli

Fiig:

A458a0